

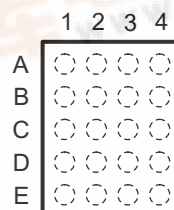
MMC, SD CARD, Memory Stick™ VOLTAGE-TRANSLATION TRANSCIEVER WITH ESD PROTECTION AND EMI FILTERING

Check for Samples: [TXS0206](#)

FEATURES

- **Level Translator**
 - V_{CCA} and V_{CCB} Range of 1.1 V to 3.6 V
 - Fast Propagation Delay (4 ns Max When Translating Between 1.8 V and 3 V)
- **Integrated EMI Filtering and ESD Protection Circuitry**
- **ESD Protection Exceeds JESD 22 (A Port)**
 - 2500-V Human-Body Model (A114-B)
 - 250-V Machine Model (A115-A)
 - 1500-V Charged-Device Model (C101)
- **±8-kV Contact Discharge IEC 61000-4-2 ESD (B-port)**

YFP PACKAGE
(TOP VIEW)



TERMINAL ASSIGNMENTS

	1	2	3	4
A	DAT2A	V_{CCA}	WP	DAT2B
B	DAT3A	CD	V_{CCB}	DAT3B
C	CMDA	GND	GND	CMDB
D	DAT0A	CLKA	CLKB	DAT0B
E	DAT1A	CLK-f	EN	DAT1B

DESCRIPTION/ORDERING INFORMATION

The TXS0206 is a level shifter for interfacing microprocessors with MultiMediaCards (MMCs), secure digital (SD) cards, and Memory Stick™ cards. It includes a high-speed level translator along with ESD protection and EMI filtering circuitry.

The voltage-level translator has two supply voltage pins. V_{CCA} as well as V_{CCB} can be operated over the full range of 1.1 V to 3.6 V. The TXS0206 enables system designers to easily interface applications processors or digital basebands to memory cards and SDIO peripherals operating at a different I/O voltage level.

Memory card standards recommend high-ESD protection for devices that connect directly to the external memory card. To meet this need, the TXS0206 incorporates ±8-kV Contact Discharge protection on the card side.

The TXS0206 is offered in a 20-bump wafer chip scale package (WCSP). This package has dimensions of 1.96 mm × 1.56 mm, with a 0.4-mm ball pitch for effective board-space savings. Memory cards are widely used in mobile phones, PDAs, digital cameras, personal media players, camcorders, set-top boxes, etc. Low static power consumption and small package size make the TXS0206 an ideal choice for these applications.

ORDERING INFORMATION⁽¹⁾

T_A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
–40°C to 85°C	WCSP – YFP (Pb-free)	Tape and reel	TXS0206YFPR	__ _3T_

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) YFP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



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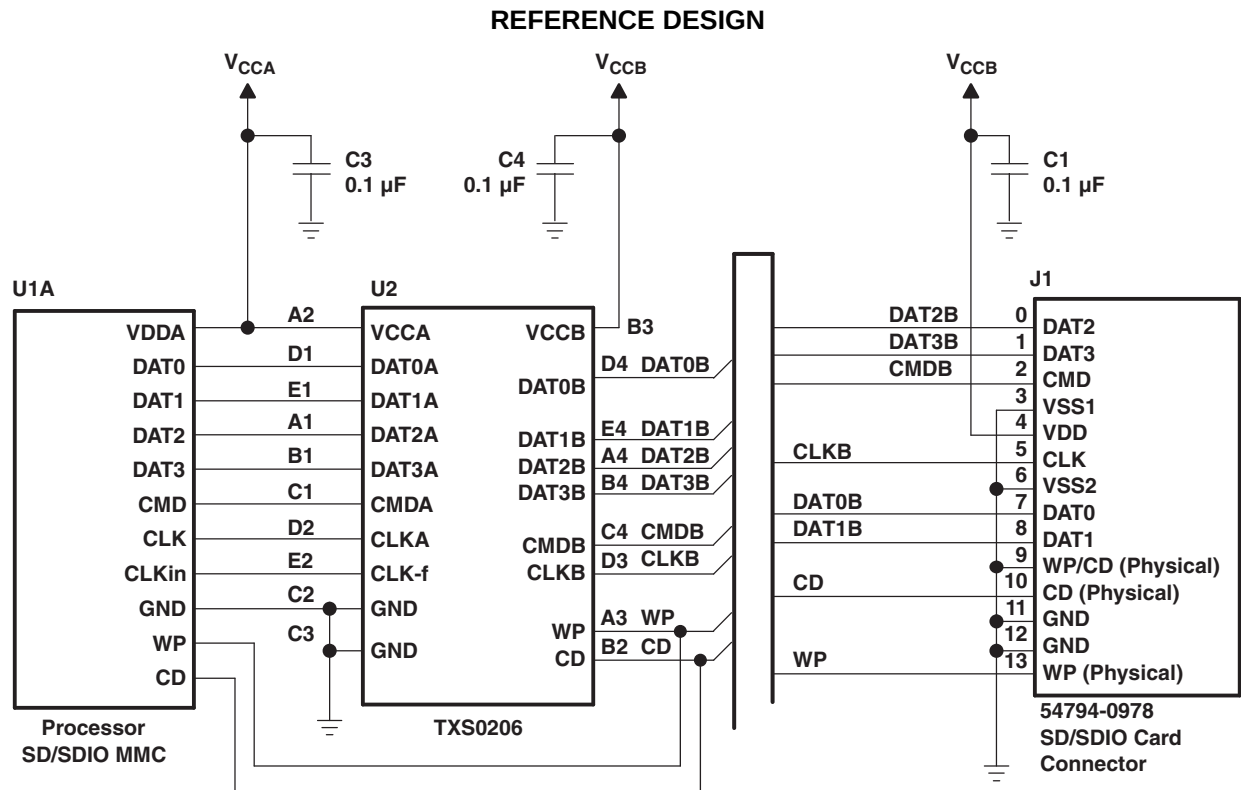
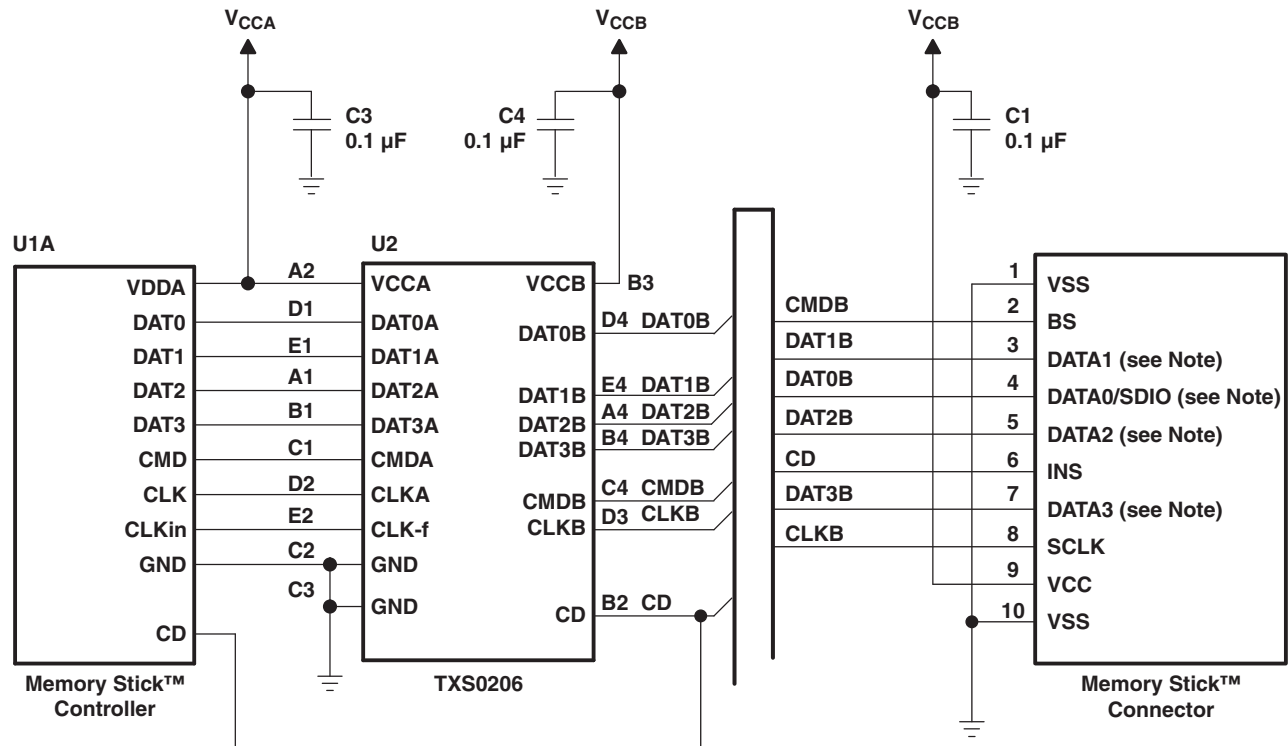


Figure 1. Interfacing With SD/SDIO Card



NOTE: The TXS0206 has integrated pullup resistor values that dynamically change value depending on whether a low or high signal is being transmitted through the device. When the output is low, the TXS0206 internal pullup value is 40 k Ω , and when the output is high, the internal pullup value change to a value of 4 k Ω . For MSA and MSH Memory Stick™ memory cards, to ensure that a valid V_{IH} (i.e., receiver input voltage high) is achieved, the internal pulldown resistors for these memory cards are not smaller than a 10-k Ω value. See the *Application Information* section of this data sheet, which explains the impact of adding too heavy (i.e., <10-k Ω value) of a pulldown resistor to the data lines of the TXS0206 device and the resulting 4-k Ω pullup/10-k Ω pulldown voltage divider network, which has a direct impact on the V_{IH} of the signal being sent into the Memory Stick™.

Figure 2. Interfacing With Memory Stick™ Card

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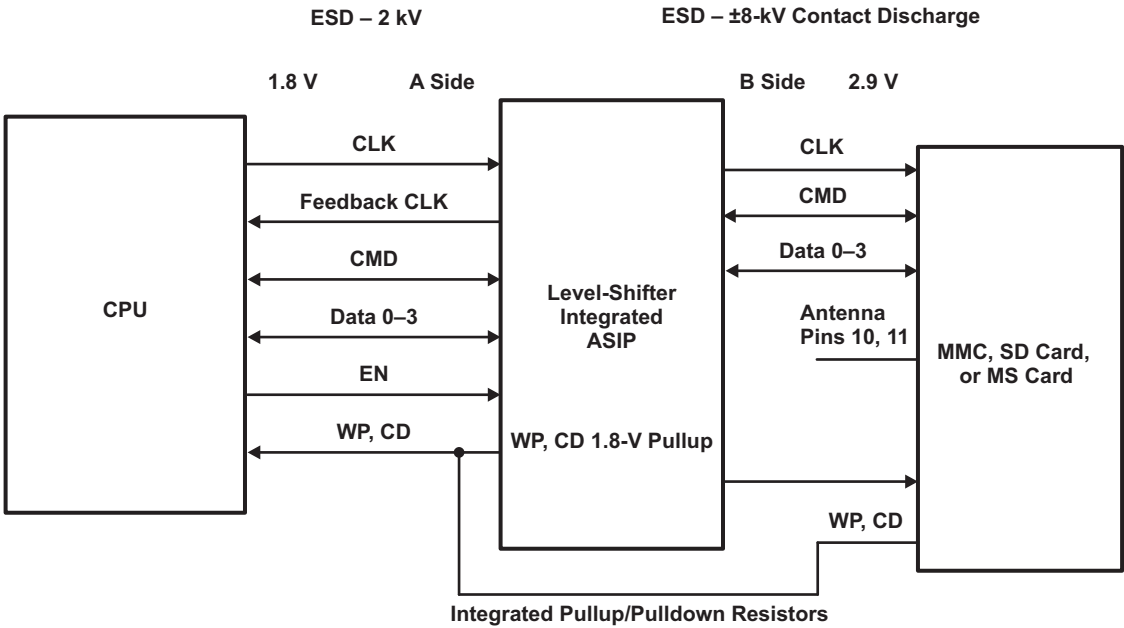


Figure 3. Typical Application Circuit

LOGIC TABLE

EN	TRANSLATOR I/Os
L	Disabled, pulled to V _{CCA} , V _{CCB} through 40 kΩ
H	Active

TERMINAL FUNCTIONS

TERMINAL		TYPE	DESCRIPTION
NO.	NAME		
A1	DAT2A	I/O	Data bit 2 connected to host. Referenced to V_{CCA} . Includes a 40-k Ω pullup resistor to V_{CCA} .
A2	V_{CCA}	Pwr	A-port supply voltage. V_{CCA} powers all A-port I/Os and control inputs.
A3	WP	O	Connected to write protect on the mechanical connector. The WP pin has an internal 100-k Ω pullup resistor to V_{CCA} .
A4	DAT2B	I/O	Data bit 2 connected to memory card. Referenced to V_{CCB} . Includes a 40-k Ω pullup resistor to V_{CCB} .
B1	DAT3A	I/O	Data bit 3 connected to host. Referenced to V_{CCA} . Includes a 40-k Ω pullup resistor to V_{CCA} .
B2	CD	O	Connected to card detect on the mechanical connector. The CD pin has an internal 100-k Ω pullup resistor to V_{CCA} .
B3	V_{CCB}	Pwr	B-port supply voltage. V_{CCB} powers all B-port I/Os.
B4	DAT3B	I/O	Data bit 3 connected to memory card. Referenced to V_{CCB} . Includes a 40-k Ω pullup resistor to V_{CCB} .
C1	CMDA	I/O	Command bit connected to host. Referenced to V_{CCA} . Includes a 40-k Ω pullup resistor to V_{CCA} .
C2, C3	GND		Ground
C4	CMDB	I/O	Command bit connected to memory card. Referenced to V_{CCB} . Includes a 40-k Ω pullup resistor to V_{CCB} .
D1	DAT0A	I/O	Data bit 0 connected to host. Referenced to V_{CCA} . Includes a 40-k Ω pullup resistor to V_{CCA} .
D2	CLKA	I	Clock signal connected to host. Referenced to V_{CCA} .
D3	CLKB	O	Clock signal connected to memory card. Referenced to V_{CCB} .
D4	DAT0B	I/O	Data bit 0 connected to memory card. Referenced to V_{CCB} . Includes a 40-k Ω pullup resistor to V_{CCB} .
E1	DAT1A	I/O	Data bit 1 connected to host. Referenced to V_{CCA} . Includes a 40-k Ω pullup resistor to V_{CCA} .
E2	CLK-f	O	Clock feedback to host for resynchronizing data to a processor. Leave unconnected if not used.
E3	EN	I	Enable/disable control. Pull EN low to place all outputs in Hi-Z state. Referenced to V_{CCA} .
E4	DAT1B	I/O	Data bit 1 connected to memory card. Referenced to V_{CCB} . Includes a 40-k Ω pullup resistor to V_{CCB} .

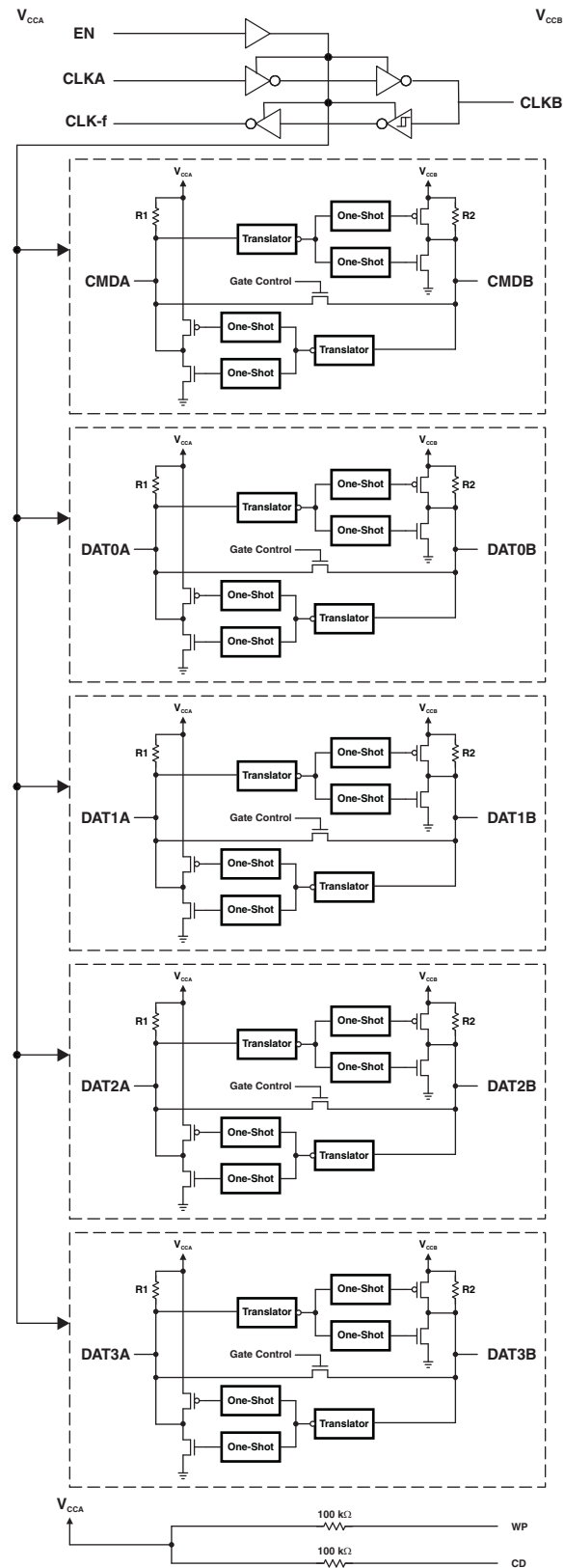


Figure 4. Logic Diagram

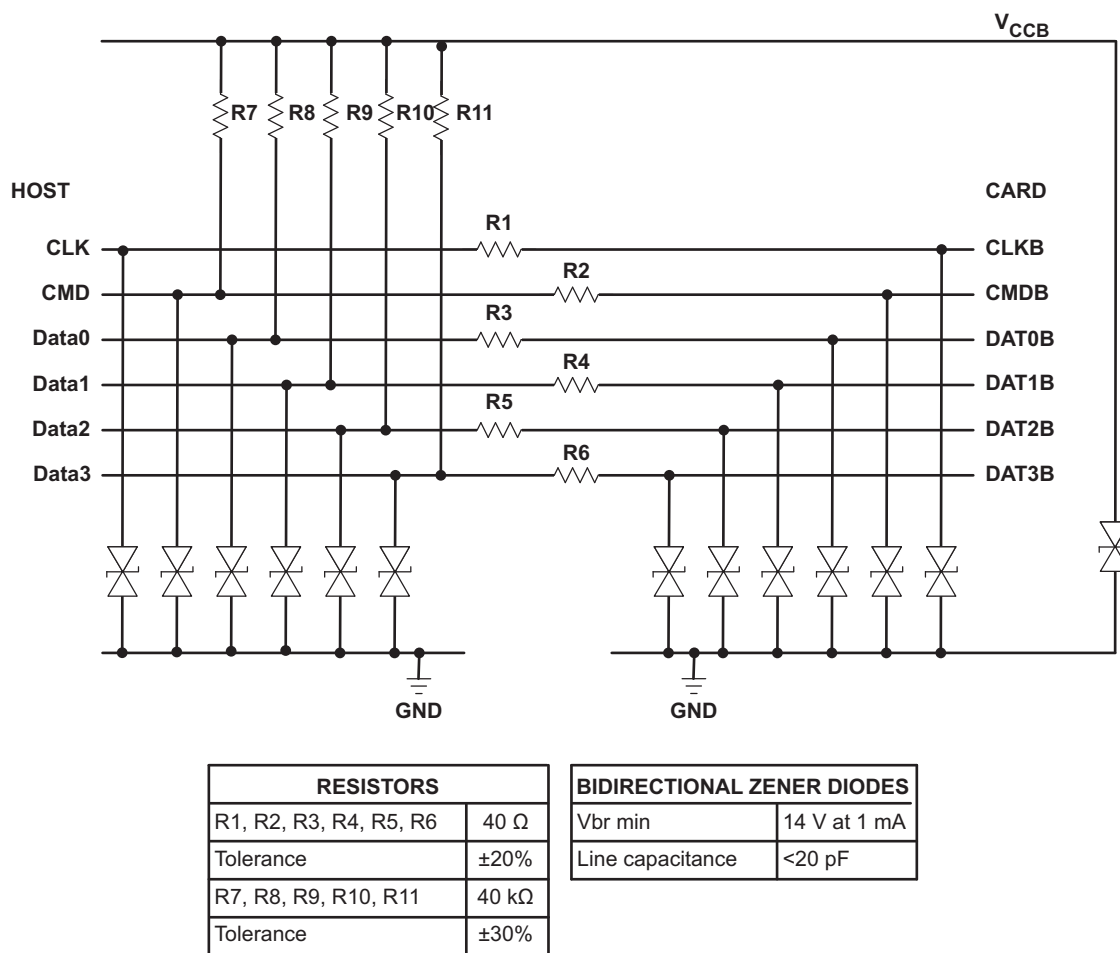


Figure 5. ASIP Block Diagram

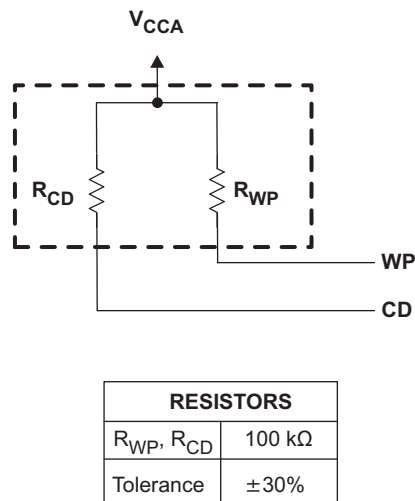


Figure 6. WP, CD Pullup Resistors

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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Level Translator

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA}	Supply voltage range		–0.5	4.6	V
V _{CCB}	Supply voltage range		–0.5	4.6	V
V _I	Input voltage range	I/O ports (A port)	–0.5	4.6	V
		I/O ports (B port)	–0.5	4.6	
		Control inputs	–0.5	4.6	
V _O	Voltage range applied to any output in the high-impedance or power-off state	A port	–0.5	4.6	V
		B port	–0.5	4.6	
V _O	Voltage range applied to any output in the high or low state	A port	–0.5	4.6	V
		B port	–0.5	4.6	
I _{IK}	Input clamp current	V _I < 0		–50	mA
I _{OK}	Output clamp current	V _O < 0		–50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V _{CCA} or GND			±100	mA
T _{stg}	Storage temperature range		–65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL IMPEDANCE RATINGS

		UNIT
θ _{JA}	Package thermal impedance ⁽¹⁾	117 °C/W

- (1) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

Level Translator

			V_{CCA}	V_{CCB}	MIN	MAX	UNIT
V_{CCA}	Supply voltage				1.1	3.6	V
V_{CCB}	Supply voltage				1.1	3.6	V
V_{IH}	High-level input voltage	A-Port CMD and DATA I/Os	1.1 V to 1.95 V	1.1 V to 1.95 V	$V_{CCI} - 0.2$	V_{CCI}	V
		B-Port CMD and DATA I/Os	1.95 V to 3.6 V	1.95 V to 3.6 V			
		EN and CLKA	1.1 V to 3.6 V	1.1 V to 3.6 V	$V_{CCI} \times 0.65$	V_{CCI}	
V_{IL}	Low-level input voltage	A-Port CMD and DATA I/Os	1.1 V to 1.95 V	1.1 V to 1.95 V	0	0.15	V
		B-Port CMD and DATA I/Os	1.95 V to 3.6 V	1.95 V to 3.6 V			
		EN and CLKA	1.1 V to 3.6 V	1.1 V to 3.6 V	0	$V_{CCI} \times 0.35$	
V_O	Output voltage	Active state			0	V_{CCO}	V
		3-state			0	3.6	
I_{OH}	High-level output current (CLK-f output)		1.1 V to 3.6 V	1.1 V to 3.6 V		-100	μ A
			1.1 V to 1.3 V			-0.5	mA
			1.4 V to 1.6 V			-1	
			1.65 V to 1.95 V			-2	
			2.3 V to 2.7 V			-4	
			3 V to 3.6 V			-8	
I_{OL}	Low-level output current (CLK-f output)		1.1 V to 3.6 V	1.1 V to 3.6 V		100	μ A
			1.1 V to 1.3 V			0.5	mA
			1.4 V to 1.6 V			1	
			1.65 V to 1.95 V			2	
			2.3 V to 2.7 V			4	
			3 V to 3.6 V			8	
I_{OH}	High-level output current (CLK output)		1.1 V to 3.6 V	1.1 V to 3.6 V		-100	μ A
				1.1 V to 1.3 V		-0.5	mA
				1.4 V to 1.6 V		-1	
				1.65 V to 1.95 V		-2	
				2.3 V to 2.7 V		-4	
				3 V to 3.6 V		-8	
I_{OL}	Low-level output current (CLK output)		1.1 V to 3.6 V	1.1 V to 3.6 V		100	μ A
				1.1 V to 1.3 V		0.5	mA
				1.4 V to 1.6 V		1	
				1.65 V to 1.95 V		2	
				2.3 V to 2.7 V		4	
				3 V to 3.6 V		8	
$\Delta t/\Delta v$	Input transition rise or fall rate					5	ns/V
T_A	Operating free-air temperature				-40	85	°C

- (1) All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

ELECTRICAL CHARACTERISTICS

Level Translator

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OH}	A port (CLK-f output)	I _{OH} = –100 µA	1.1 V to 3.6 V	1.1 V to 3.6 V	V _{CCA} × 0.8			V
		I _{OH} = –0.5 mA	1.1 V		0.8			
		I _{OH} = –1 mA	1.4 V		1.05			
		I _{OH} = –2 mA	1.65 V		1.2			
		I _{OH} = –4 mA	2.3 V		1.75			
		I _{OH} = –8 mA	3 V		2.3			
	A port (DAT and CMD outputs)	I _{OH} = –20 µA	1.1 V to 3.6 V		V _{CCA} × 0.8			
V _{OL}	A port (CLK-f output)	I _{OL} = 100 µA	1.1 V to 3.6 V	1.1 V to 3.6 V			V _{CCA} × 0.8	V
		I _{OL} = 0.5 mA	1.1 V				0.35	
		I _{OL} = 1 mA	1.4 V				0.35	
		I _{OL} = 2 mA	1.65 V				0.45	
		I _{OL} = 4 mA	2.3 V				0.55	
		I _{OL} = 8 mA	3 V				0.7	
	A port (DAT and CMD outputs)	I _{OL} = 135 µA	1.1 V to 3.6 V				0.4	V
		I _{OL} = 180 µA					0.4	
		I _{OL} = 220 µA					0.4	
		I _{OL} = 300 µA					0.4	
		I _{OL} = 400 µA					0.55	
V _{OH}	B port (CLK output)	I _{OH} = –100 µA	1.1 V to 3.6 V	1.1 V to 3.6 V	V _{CCA} × 0.8			V
		I _{OH} = –0.5 mA		1.1 V	0.8			
		I _{OH} = –1 mA		1.4 V	1.05			
		I _{OH} = –2 mA		1.65 V	1.2			
		I _{OH} = –4 mA		2.3 V	1.75			
		I _{OH} = –8 mA		3 V	2.3			
	B port (DAT output)	I _{OH} = –20 µA		1.1 V to 3.6 V	V _{CCA} × 0.8			

(1) All typical values are at T_A = 25°C.

ELECTRICAL CHARACTERISTICS

Level Translator (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OL}	B port	I _{OL} = 100 µA	1.1 V to 3.6 V	1.1 V to 3.6 V	V _{CCA} × 0.8			V
		I _{OL} = 0.5 mA		1.1 V	0.35			
		I _{OL} = 1 mA		1.4 V	0.35			
		I _{OL} = 2 mA		1.65 V	0.45			
		I _{OL} = 4 mA		2.3 V	0.55			
		I _{OL} = 8 mA		3 V	0.7			
	B port (DAT output)	I _{OL} = 135 µA	1.1 V to 3.6 V	1.1 V to 3.6 V	0.4			V
		I _{OL} = 180 µA		1.4 V	0.4			
		I _{OL} = 220 µA		1.65 V	0.4			
		I _{OL} = 300 µA		2.3 V	0.4			
		I _{OL} = 400 µA		3 V	0.55			
I _I	Control inputs	V _I = V _{CCA} or GND		1.1 V to 3.6 V	±1			µA
I _{CCA}		V _I = V _{CCi} or GND, I _O = 0	1.1 V to 3.6 V	1.1 V to 3.6 V	6			µA
I _{CCB}		V _I = V _{CCi} or GND, I _O = 0	1.1 V to 3.6 V	1.1 V to 3.6 V	5			µA
C _{io}	A port				5.5		6.5	pF
	B port				15		17.5	
C _i	Control inputs	V _I = V _{CCA} or GND			3.5		4.5	pF
	Clock input				3		4	

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TIMING REQUIREMENTS

$$V_{CCA} = 1.2\text{ V} \pm 0.1\text{ V}$$

over recommended operating free-air temperature range (unless otherwise noted)

			$V_{CCB} = 1.2\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate	Command	Push-pull driving	30		40		40		40		40		Mbps
		Open-drain driving	0.9		1		1		1		1		
	Clock	Push-pull driving	30		40		50		60		60		MHz
	Data		30		40		40		40		40		Mbps
t_w Pulse duration	Command	Push-pull driving	33		25		25		25		25		ns
		Open-drain driving	1		1		1		1		1		μ s
	Clock	Push-pull driving	16.7		12.5		10		8.3		8.3		ns
	Data		33		25		25		25		25		ns

TIMING REQUIREMENTS

$$V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$$

over recommended operating free-air temperature range (unless otherwise noted)

			$V_{CCB} = 1.2\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate	Command	Push-pull driving	30		60		60		60		60		Mbps
		Open-drain driving	1		1		1		1		1		
	Clock	Push-pull driving	50		60		60		60		60		MHz
	Data		30		60		60		60		60		Mbps
t_w Pulse duration	Command	Push-pull driving	33		17		17		17		17		ns
		Open-drain driving	1		1		1		1		1		μ s
	Clock	Push-pull driving	10		8.3		8.3		8.3		8.3		ns
	Data		33		17		17		17		17		ns

TIMING REQUIREMENTS

$$V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$$

over recommended operating free-air temperature range (unless otherwise noted)

			$V_{CCB} = 1.2\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate	Command	Push-pull driving	30		60		60		60		60		Mbps
		Open-drain driving	1		1		1		1		1		
	Clock	Push-pull driving	50		60		60		60		60		MHz
	Data		30		60		60		60		60		Mbps
t_w	Pulse duration	Push-pull driving	33		17		17		17		17		ns
		Open-drain driving	1		1		1		1		1		μs
	Clock	Push-pull driving	10		8.3		8.3		8.3		8.3		ns
	Data		33		17		17		17		17		ns

TIMING REQUIREMENTS

$$V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$$

over recommended operating free-air temperature range (unless otherwise noted)

			$V_{CCB} = 1.2\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate	Command	Push-pull driving	30		60		60		60		60		Mbps
		Open-drain driving	1		1		1		1		1		
	Clock	Push-pull driving	60		60		60		60		60		MHz
	Data		30		60		60		60		60		Mbps
t_w Pulse duration	Command	Push-pull driving	33		17		17		17		17		ns
		Open-drain driving	1		1		1		1		1		μs
	Clock	Push-pull driving	8.3		8.3		8.3		8.3		8.3		ns
	Data		33		17		17		17		17		ns

TIMING REQUIREMENTS

$$V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$$

over recommended operating free-air temperature range (unless otherwise noted)

			$V_{CCB} = 1.2\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate	Command	Push-pull driving	30		60		60		60		60		Mbps
		Open-drain driving	0.9		1		1		1		1		
	Clock	Push-pull driving	55		55		55		55		55		MHz
	Data		30		60		60		60		60		Mbps
t_w Pulse duration	Command	Push-pull driving	33		17		17		17		17		ns
		Open-drain driving	1		1		1		1		1		μs
	Clock	Push-pull driving	9		9		9		9		9		ns
	Data		33		17		17		17		17		ns

SWITCHING CHARACTERISTICS**V_{CCA} = 1.2 V ± 0.1 V**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 1.2 V ± 0.1 V		V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	CMDA	CMDB	Push-pull driving	15.3		12.2		10.8		10.4		10.8		ns
			Open-drain driving (H-to-L)	4.1	16.6	3.7	12.6	3.4	11.5	3.3	10.6	3.2	10.3	
			Open-drain driving (L-to-H)	204	308	164	256	133	224	95	175	71	147	
	CMDB	CMDA	Push-pull driving	19.7		15.1		13.4		12		11.2		
			Open-drain driving (H-to-L)	4.7	19.4	3.8	12.4	3.4	10.5	3.1	9.2	2.9	9.4	
			Open-drain driving (L-to-H)	211	353	170	304	139	282	101	243	77	204	
	CLKA	CLKB	Push-pull driving	15.6		12.3		11.5		10.9		11.7		
	DATxA	DATxB	Push-pull driving	15.9		12.6		11.2		10.7		11.1		
	DATxB	DATxA		18.2		14.3		12.8		11.5		10.6		
	CLKA	CLK-f	Push-pull driving	37.9		30.7		26.8		24.7		24.2		
t _{en}	EN	B-port	Push-pull driving	1		1		1		1		1		μs
	EN	A-port	Push-pull driving	1		1		1		1		1		
t _{dis}	EN	B-port	Push-pull driving	68		55		46		40		38		ns
	EN	A-port	Push-pull driving	62		56		48		40		37		
t _{rA}	CMDA rise time		Push-pull driving	1.7	14.1	1.5	13	1.5	12.7	1.6	12.2	1.9	11.9	ns
			Open-drain driving	170	260	128	205	96	171	57	120	32	91	
	CLK-f rise time		Push-pull driving	0.6	10.6	0.6	10.9	0.6	12	0.6	12.3	0.6	12.7	
	DATxA rise time			1.7	13.7	1.5	12.6	1.5	12	1.6	11.6	1.9	11.5	
t _{rB}	CMDB rise time		Push-pull driving	1.9	12.4	2.3	9.2	1.9	7.3	1.8	6.7	1.7	3.9	ns
			Open-drain driving	175	300	145	261	118	245	86	214	66	181	
	CLKB rise time		Push-pull driving	1	7.7	0.8	7.1	0.8	6.2	1.7	4.8	1.7	4.3	
	DATxB rise time			2.9	11.8	2.3	8.9	1.9	7.4	0.9	4.7	0.4	6.8	
t _{fA}	CMDA fall time		Push-pull driving	1	8	1	5.4	1	4.5	1	3.9	0.8	4	ns
			Open-drain driving	2.3	8.3	1.9	4.9	1.7	4.4	1.6	3.9	1.6	3.7	
	CLK-f fall time		Push-pull driving	1	5.8	1	4.6	1	4.1	1	3.8	1	4	
	DATxA fall time			1.8	8	1.3	5.4	1	4.5	1	3.9	1	3.8	
t _{fB}	CMDB fall time		Push-pull driving	2.1	7.9	1.8	5.2	1.7	4.6	1.6	4.5	1.5	4.3	ns
			Open-drain driving	1.9	8.3	1.5	5.9	1.3	5.1	1.1	4.3	1	4.2	
	CLKB fall time		Push-pull driving	2	7.1	1.8	5.4	1.8	4.5	1.7	4	1.6	3.9	
	DATxB fall time			2.1	8.5	1.1	6.4	0.9	5	1	3.9	1.1	4.8	
t _{SK(O)}	Channel-to-channel skew		Push-pull driving	1		1		1		1		1		ns
Max data rate	Command		Push-pull driving	30		40		40		40		40		Mbps
			Open-drain driving	0.9		1		1		1		1		
	Clock		Push-pull driving	30		40		50		60		60		MHz
	Data			30		40		40		40		40		Mbps

SWITCHING CHARACTERISTICS

$$V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$$

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 1.2 V ± 0.1 V		V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	CMDA	CMDB	Push-pull driving	12		8.6		6.9		6.1		6		ns
			Open-drain driving (H-to-L)	3.7	12.8	3.2	8.7	2.9	7.6	2.7	6.6	2.7	6.5	
			Open-drain driving (L-to-H)	192	297	191	295	157	252	112	180	83	138	
	CMDB	CMDA	Push-pull driving	15.2		9.8		8		6.8		6.3		
			Open-drain driving (H-to-L)	3.7	20.4	2.9	11.8	2.5	9.4	2.2	7.3	2.1	6.6	
			Open-drain driving (L-to-H)	199	337	196	316	162	282	117	214	87	177	
	CLKA	CLKB	Push-pull driving	12.3		8.7		7.7		6.1		6.2		
	DATxA	DATxB	Push-pull driving	12.5		8.9		7.2		6.2		6.1		
	DATxB	DATxA		13.9		9.2		7.6		6.5		6.1		
	CLKA	CLK-f	Push-pull driving	29		20		16		13		12		
t _{en}	EN	B-port	Push-pull driving	1		1		1		1		1		μs
	EN	A-port	Push-pull driving	1		1		1		1		1		
t _{dis}	EN	B-port	Push-pull driving	57		53		46		39		37		ns
	EN	A-port	Push-pull driving	58		54		46		38		35		
t _{rA}	CMDA rise time		Push-pull driving	1.6	10.5	0.4	9.5	0.2	8.9	0.4	8.3	1	7.9	ns
			Open-drain driving	166	254	157	247	121	203	74	127	44	85	
	CLK-f rise time		Push-pull driving	0.5	5.5	0.5	5.5	0.5	6.2	0.5	7	0.5	7.2	
	DATxA rise time			2	10.3	0.7	9.4	0.5	8.9	0.6	8.4	0.7	8.3	
t _{rB}	CMDB rise time		Push-pull driving	1.9	11.2	2	8	1.9	6.5	0.5	5.6	0.5	3.1	ns
			Open-drain driving	157	273	163	264	135	253	96	196	71	165	
	CLKB rise time		Push-pull driving	1.3	7.5	0.6	6.7	0.4	5.9	1.5	4.9	1.9	4.3	
	DATxB rise time			2.2	10.9	2	8.4	1.7	6.9	0.8	5	0.6	4	
t _{fA}	CMDA fall time		Push-pull driving	1.5	5.5	1.3	3.8	0.9	2.9	0.8	2.3	0.8	2.3	ns
			Open-drain driving	2.3	8	2	4.8	1.8	4.2	1.7	3.7	1.6	3.5	
	CLK-f fall time		Push-pull driving	0.4	3.9	0.4	3.7	0.4	4	0.4	3.7	0.4	6.8	
	DATxA fall time			0.8	6	0.6	4.8	0.1	4.1	0.1	3.8	0.1	3.8	
t _{fB}	CMDB fall time		Push-pull driving	1	11.6	1.5	7.1	1.5	5.8	1.4	5.4	1.6	3.6	ns
			Open-drain driving	1.7	5.2	1.5	3.8	1.2	3	1	2.3	0.9	2.3	
	CLKB fall time		Push-pull driving	1.1	10.8	1	8.8	1.8	6	1.7	4.1	1.6	3.9	
	DATxB fall time			1.1	13.3	1.2	7.7	1.2	6.5	2.3	4.3	2.5	4.2	
t _{SK(O)}	Channel-to-channel skew		Push-pull driving	1		1		1		1		1		ns
Max data rate	Command		Push-pull driving	30		60		60		60		60		Mbps
			Open-drain driving	1		1		1		1		1		
	Clock		Push-pull driving	50		60		60		60		60		MHz
	Data			30		60		60		60		60		Mbps

SWITCHING CHARACTERISTICS

$V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 1.2 V ± 0.1 V		V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	CMDA	CMDB	Push-pull driving	11.3		7.3		5.7		4.6		4.4		ns
			Open-drain driving (H-to-L)	3.4	11.8	2.9	7.6	2.7	6.5	2.5	5.5	2.4	5.1	
			Open-drain driving (L-to-H)	179	286	183	288	168	286	121	201	89	151	
	CMDB	CMDA	Push-pull driving	13.2		8.3		6.5		5.2		4.8		
			Open-drain driving (H-to-L)	3.5	19.7	2.8	11.1	2.4	8.6	2.1	6.4	2	5.7	
			Open-drain driving (L-to-H)	186	323	190	304	173	303	125	215	93	166	
	CLKA	CLKB	Push-pull driving	11.6		7.7		6.2		4.7		4.5		
	DATxA	DATxB	Push-pull driving	11.7		7.5		5.8		4.7		4.4		
	DATxB	DATxA		12.1		7.9		6.3		5		4.6		
	CLKA	CLK-f	Push-pull driving	25.1		16.5		12		8.9		7.9		
t _{en}	EN	B-port	Push-pull driving	1		1		1		1		1		μs
	EN	A-port	Push-pull driving	1		1		1		1		1		
t _{dis}	EN	B-port	Push-pull driving	39		37		37		35		35		ns
	EN	A-port	Push-pull driving	49		47		47		38		35		
t _{rA}	CMDA rise time		Push-pull driving	1.8	8.4	1.2	6.8	1.1	5.9	1.1	5.9	1.6	5.8	ns
			Open-drain driving	154	246	155	262	135	238	85	150	52	99	
	CLK-f rise time		Push-pull driving	0.4	4	0.4	4.3	0.4	4.7	0.4	4.5	0.4	4.1	
	DATxA rise time			1.9	8.6	1.2	7.1	0.9	6.8	1	6.3	1.3	6.1	
t _{rB}	CMDB rise time		Push-pull driving	1.8	10.2	2	7.7	1.7	6.5	1	5.2	1.7	3.1	ns
			Open-drain driving	137	251	148	245	141	251	100	184	73	142	
	CLKB rise time		Push-pull driving	1.5	7.3	0.7	6.6	0.4	5.9	1.5	4.9	1.9	4.3	
	DATxB rise time			2.3	10.3	1.8	8	1.5	6.8	0.9	5.2	0.2	5	
t _{fA}	CMDA fall time		Push-pull driving	0.6	4.5	0.4	3.8	0.2	3.3	0.2	2.9	0.2	3.1	ns
			Open-drain driving	2.3	7.9	2	4.8	1.8	4.2	1.7	3.7	1.6	3.5	
	CLK-f fall time		Push-pull driving	0.1	2	0.2	2.2	0.7	1.6	0.7	1.5	0.1	3	
	DATxA fall time			1	4.3	0.8	3.6	1	2.7	0.1	2.7	0.2	2.6	
t _{fB}	CMDB fall time		Push-pull driving	1	10.3	1.4	6.8	1.8	5.4	1.6	5	1.6	3.6	ns
			Open-drain driving	1.4	4	1.3	3	1.2	2.6	0.9	1.9	0.8	1.8	
	CLKB fall time		Push-pull driving	1.1	10.8	1	10.3	1.4	6.3	1.8	4.2	1.7	4	
	DATxB fall time			1	11.8	15	7	1.2	6.3	1.6	4.9	0.8	3.6	
t _{SK(O)}	Channel-to-channel skew		Push-pull driving	1		1		1		1		1		ns
Max data rate	Command		Push-pull driving	30		60		60		60		60		Mbps
			Open-drain driving	1		1		1		1		1		
	Clock		Push-pull driving	50		60		60		60		60		MHz
	Data			30		60		60		60		60		Mbps

SWITCHING CHARACTERISTICS

$$V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$$

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 1.2 V ± 0.1 V		V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	CMDA	CMDB	Push-pull driving	10.6		6.5		4.9		3.7		3.3		ns
			Open-drain driving (H-to-L)	3.2	10.9	2.7	6.7	2.4	5.5	2.2	4.4	2.1	4.1	
			Open-drain driving (L-to-H)	156	253	162	258	149	261	126	249	98	190	
	CMDB	CMDA	Push-pull driving	12.5		7.4		5.6		4.1		3.6		
			Open-drain driving (H-to-L)	3.5	19.2	2.7	10.5	2.3	7.9	2	5.7	1.9	4.8	
			Open-drain driving (L-to-H)	163	295	169	273	158	274	131	261	99	202	
	CLKA	CLKB	Push-pull driving	10.8		6.8		5.4		3.7		3.4		
	DATxA	DATxB	Push-pull driving	10.9		6.7		5		3.7		3.3		
	DATxB	DATxA		11.5		7.1		5.4		3.9		3.5		
	CLKA	CLK-f	Push-pull driving	23.7		14.9		10.2		6.8		5.7		
t _{en}	EN	B-port	Push-pull driving	1		1		1		1		1		μs
	EN	A-port	Push-pull driving	1		1		1		1		1		
t _{dis}	EN	B-port	Push-pull driving	48		45		45		38		36		ns
	EN	A-port	Push-pull driving	45		38		38		38		35		
t _{rA}	CMDA rise time		Push-pull driving	1.9	4.7	1.7	4.4	1.7	3.8	1.9	3.2	2.3	3.3	ns
			Open-drain driving	135	216	136	237	121	228	96	201	62	141	
	CLK-f rise time		Push-pull driving	0.8	1.6	0.3	1.9	0.6	1.8	0.7	1.5	0.7	1.3	
	DATxA rise time			1.9	6.1	1.8	4.5	1.7	4.1	1.9	4	1.8	4.2	
t _{rB}	CMDB rise time		Push-pull driving	1.7	10.8	2.9	7.6	1.8	6.6	1.5	5.2	1.5	3.8	ns
			Open-drain driving	102	205	116	197	112	207	101	214	76	165	
	CLKB rise time		Push-pull driving	1.6	7.3	0.5	6.8	0.4	5.8	1.6	5	1.7	4.4	
	DATxB rise time			2.2	10.3	1.9	7.9	1.8	6.6	1.4	5.3	0.9	4.4	
t _{fA}	CMDA fall time		Push-pull driving	0.4	2.4	0.4	1.6	0.4	1.5	0.5	1.5	0.3	1.4	ns
			Open-drain driving	2.2	7.6	1.9	4.8	1.8	4.2	1.7	3.7	1.6	3.5	
	CLK-f fall time		Push-pull driving	0.3	2.2	0.3	2.7	0.3	2.6	0.3	2.4	0.3	2.8	
	DATxA fall time			0.4	4	0.4	3.6	0.4	3.2	0.5	2.9	0.3	2.6	
t _{fB}	CMDB fall time		Push-pull driving	1	13.4	1.8	7.2	1.7	6.3	1.6	5.6	1.6	3.7	ns
			Open-drain driving	1	2.3	1	1.7	1	1.7	1	1.6	0.8	1.4	
	CLKB fall time		Push-pull driving	1.1	12.7	1	11.3	0.9	8.7	1.8	4.5	1.7	4.1	
	DATxB fall time			1	16	0.7	9	0.8	7	0.8	4.9	0.2	4	
t _{SK(O)}	Channel-to-channel skew		Push-pull driving	1		1		1		1		1		ns
Max data rate	Command		Push-pull driving	30		60		60		60		60		Mbps
			Open-drain driving	1		1		1		1		1		
	Clock		Push-pull driving	50		60		60		60		60		MHz
	Data			30		60		60		60		60		Mbps

SWITCHING CHARACTERISTICS

$$V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$$

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 1.2 V ± 0.1 V		V _{CCB} = 1.5 V ± 0.1 V		V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	CMDA	CMDB	Push-pull driving	12.5		7.2		5.3		3.8		3.2		ns
			Open-drain driving (H-to-L)	3.2	10.6	2.7	6.4	2.4	5.2	2.1	4.1	2	3.7	
			Open-drain driving (L-to-H)	136	212	141	235	129	235	112	233	101	201	
	CMDB	CMDA	Push-pull driving	10.7		6.6		5.1		3.4		3		
			Open-drain driving (H-to-L)	4.3	16.4	3.3	8.7	2.8	6.6	2.4	4.6	2.2	3.6	
			Open-drain driving (L-to-H)	142	273	148	246	139	248	122	248	105	212	
	CLKA	CLKB	Push-pull driving	10.8		6.5		4.8		3.5		3.1		
	DATxA	DATxB	Push-pull driving	11.5		6.9		5.1		3.7		3.2		
	DATxB	DATxA		23.6		14.4		9.6		6.2		5.1		
	CLKA	CLK-f	Push-pull driving	17.1		9.1		6.8		4.8		4.2		
t _{en}	EN	B-port	Push-pull driving	1		1		1		1		1		μs
	EN	A-port	Push-pull driving	1		1		1		1		1		
t _{dis}	EN	B-port	Push-pull driving	38		34		34		34		34		ns
	EN	A-port	Push-pull driving	45		37		36		36		35		
t _{rA}	CMDA rise time		Push-pull driving	0.7	5.6	0.7	5	0.7	4.2	0.8	4.1	1	4.2	ns
			Open-drain driving	117	178	118	213	104	206	85	194	74	155	
	CLK-f rise time		Push-pull driving	0.7	1.5	0.5	1.7	0.7	1.5	0.7	1.4	0.7	1.4	
	DATxA rise time			0.9	5	1.1	3.9	1.3	3.4	1.4	3.3	1.1	3	
t _{rB}	CMDB rise time		Push-pull driving	1.7	10.8	2.3	7.4	2.2	6.4	2	5	1.9	4	ns
			Open-drain driving	69	167	84	156	83	167	79	185	79	166	
	CLKB rise time		Push-pull driving	1	7.7	0.3	7.1	0.5	5.9	1.6	5.1	1.9	4.4	
	DATxB rise time			2.1	10.5	2	7.9	2	6.6	1.8	5.3	1	14	
t _{fA}	CMDA fall time		Push-pull driving	0.3	2.8	0.4	2.4	0.4	2	0.4	2	1	2.3	ns
			Open-drain driving	2	7.6	1.8	5	1.7	4.4	1.6	3.9	1.6	3.7	
	CLK-f fall time		Push-pull driving	0.6	1.3	0.6	1.3	0.6	1.3	0.6	1.3	0.6	1.3	
	DATxA fall time			0.3	2.7	0.4	2.3	0.4	1.4	0.4	1.8	0.5	1.7	
t _{fB}	CMDB fall time		Push-pull driving	1	13.3	0.7	7.9	0.9	6.2	0.8	6.3	1	5	ns
			Open-drain driving	0.7	1.5	0.7	1.4	0.8	1.4	0.9	1.3	0.9	1.3	
	CLKB fall time		Push-pull driving	1	15.5	1	9.1	0.9	7.8	0.9	5.1	0.9	4.3	
	DATxB fall time			1	15	0.9	6.8	0.9	6.8	0.8	6.9	0.8	5	
t _{SK(O)}	Channel-to-channel skew		Push-pull driving	1		1		1		1		1		ns
Max data rate	Command		Push-pull driving	30		60		60		60		60		Mbps
			Open-drain driving	0.9		1		1		1		1		
	Clock		Push-pull driving	55		55		55		55		55		MHz
	Data			30		60		60		60		60		Mbps

OPERATING CHARACTERISTICS

 $T_A = 25^{\circ}\text{C}$, $V_{CCA} = 1.2\text{ V}$

PARAMETER			TEST CONDITIONS	V_{CCB} TYP						UNIT
				1.2 V	1.5 V	1.8 V	2.5 V	3 V	3.3 V	
C_{pdA} (1)	A-port input, B-port output	CLK Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	15	15	14.9	14.9	15	15	pF
		DATA Enabled		6.3	6.4	6.5	6.5	6.5	6.5	
	B-port input, A-port output	DATA Enabled		12.5	12.3	12.3	12.1	12	11.9	
		CLK Disabled		0.2	0.2	0.2	0.3	0.3	0.3	
	A-port input, B-port output	DATA Disabled		1.2	1.2	1.2	1.2	1.2	1.2	
		DATA Disabled		0.2	0.2	0.2	0.3	0.3	0.3	
C_{pdB} (1)	A-port input, B-port output	DATA Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	26.2	27.3	28.2	29.7	30	31.2	pF
		CLK Enabled		25.7	25.6	25.6	26.4	27	28.1	
	B-port input, A-port output	DATA Enabled		13.7	12.2	11.4	12	12.5	12.9	
		DATA Disabled		0.6	0.5	0.5	0.5	0.5	0.6	
	A-port input, B-port output	CLK Disabled		0.6	0.5	0.5	0.5	0.5	0.6	
		DATA Disabled		1.2	1.2	1.2	1	1	0.9	

(1) Power dissipation capacitance per transceiver

OPERATING CHARACTERISTICS

 $T_A = 25^{\circ}\text{C}$, $V_{CCA} = 1.5\text{ V}$

PARAMETER			TEST CONDITIONS	V_{CCB} TYP						UNIT
				1.2 V	1.5 V	1.8 V	2.5 V	3 V	3.3 V	
C_{pdA} (1)	A-port input, B-port output	CLK Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	15	15	15	14.9	14.9	14.9	pF
		DATA Enabled		6.4	6.3	6.2	6	6	6	
	B-port input, A-port output	DATA Enabled		13.2	12.3	12.2	12	12	11.9	
		CLK Disabled		0.1	0.1	0.1	0.1	0.1	0.1	
	A-port input, B-port output	DATA Disabled		1.2	1.2	1.2	1.2	1.2	1.2	
		DATA Disabled		0.1	0.1	0.1	0.1	0.1	0.1	

(1) Power dissipation capacitance per transceiver

[查询 TXS0206 供应链](#)
OPERATING CHARACTERISTICS (continued) $T_A = 25^\circ\text{C}$, $V_{CCA} = 1.5\text{ V}$

PARAMETER			TEST CONDITIONS	V_{CCB} TYP						UNIT
				1.2 V	1.5 V	1.8 V	2.5 V	3 V	3.3 V	
C_{pdB} ⁽¹⁾	A-port input, B-port output	DATA Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	25.8	26.3	27.3	29.2	29.2	30.6	pF
	B-port input, A-port output	CLK Enabled		25.8	25.6	25.6	26.2	26.2	27.2	
	B-port input, A-port output	DATA Enabled		13.7	12.3	11.4	12	12	12.8	
	A-port input, B-port output	DATA Disabled		0.1	0.1	0.1	0.1	0.1	0.1	
	B-port input, A-port output	CLK Disabled		0.1	0.1	0.1	0.1	0.1	0.1	
	B-port input, A-port output	DATA Disabled		1.2	1.2	1.1	1	1	0.9	

OPERATING CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_{CCA} = 1.8\text{ V}$

PARAMETER			TEST CONDITIONS	V_{CCB} TYP						UNIT
				1.2 V	1.5 V	1.8 V	2.5 V	3 V	3.3 V	
C_{pdA} ⁽¹⁾	A-port input, B-port output	CLK Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	15.2	15.1	15.1	15	15	15	pF
	B-port input, A-port output	DATA Enabled		6.7	6.2	5.8	5.4	5.4	5.3	
	B-port input, A-port output	DATA Enabled		13.9	13.1	12.4	12.1	12	11.9	
	A-port input, B-port output	CLK Disabled		0.1	0.1	0.1	0.1	0.1	0.1	
	A-port input, B-port output	DATA Disabled		1.3	1.3	1.3	1.3	1.3	1.3	
	B-port input, A-port output	DATA Disabled		0.1	0.1	0.1	0.1	0.1	0.1	
C_{pdB} ⁽¹⁾	A-port input, B-port output	DATA Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	25.9	26.1	26.7	28.8	28.8	30.3	pF
	B-port input, A-port output	CLK Enabled		25.8	25.6	25.6	26.2	26.2	27	
	B-port input, A-port output	DATA Enabled		13.6	12.2	11.5	12.1	12.1	12.9	
	A-port input, B-port output	DATA Disabled		0.2	0.1	0.1	0.1	0.1	0.1	
	B-port input, A-port output	CLK Disabled		0.2	0.1	0.1	0.1	0.1	0.1	
	B-port input, A-port output	DATA Disabled		1.2	1.2	1.1	1	1	0.8	

(1) Power dissipation capacitance per transceiver

OPERATING CHARACTERISTICS

 $T_A = 25^\circ\text{C}$, $V_{CCA} = 2.5\text{ V}$

PARAMETER			TEST CONDITIONS	V_{CCB} TYP						UNIT
				1.2 V	1.5 V	1.8 V	2.5 V	3 V	3.3 V	
C_{pdA} (1)	A-port input, B-port output	CLK Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	16.2	16	15.9	15.8	15.8	15.7	pF
		DATA Enabled		7.3	6.5	5.9	5.5	5.4	5.3	
	B-port input, A-port output	DATA Enabled		15.3	14.6	14	13	12.8	12.5	
		CLK Disabled		0.1	0.1	0.1	0.1	0.1	0.1	
	A-port input, B-port output	DATA Disabled		1.3	1.3	1.3	1.3	1.3	1.3	
		DATA Disabled		0.1	0.1	0.1	0.1	0.1	0.1	
C_{pdB} (1)	A-port input, B-port output	DATA Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	25.6	25.8	26.2	27.6	29	29.5	pF
		CLK Enabled		25.9	25.7	25.7	26.2	26.5	26.9	
	B-port input, A-port output	DATA Enabled		13.6	12.2	11.5	12.3	12.7	13.2	
		DATA Disabled		0.3	0.1	0.1	0.1	0.1	0.1	
	A-port input, B-port output	CLK Disabled		0.3	0.1	0.1	0.1	0.1	0.1	
		DATA Disabled		1.2	1.2	1.1	1	0.9	0.8	

(1) Power dissipation capacitance per transceiver

OPERATING CHARACTERISTICS

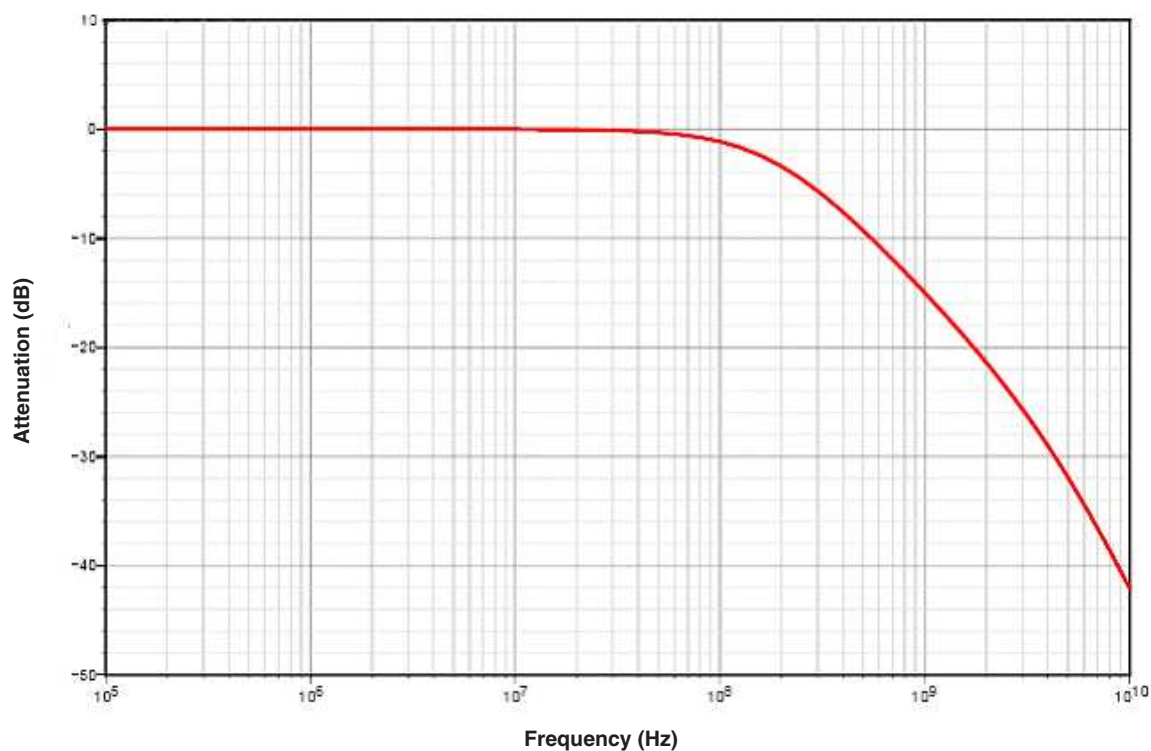
 $T_A = 25^\circ\text{C}$, $V_{CCA} = 3.3\text{ V}$

PARAMETER			TEST CONDITIONS	V_{CCB} TYP						UNIT
				1.2 V	1.5 V	1.8 V	2.5 V	3 V	3.3 V	
C_{pdA} (1)	A-port input, B-port output	CLK Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	18.3	17.7	17.5	17.3	17.2	17.1	pF
		DATA Enabled		8.1	7	6.2	5.7	5.6	5.6	
	B-port input, A-port output	DATA Enabled		17	16.1	15.6	14.8	14.4	14	
		CLK Disabled		0.1	0.1	0.1	0.1	0.1	0.1	
	A-port input, B-port output	DATA Disabled		1.3	1.3	1.3	1.3	1.3	1.3	
		DATA Disabled		0.1	0.1	0.1	0.1	0.1	0.1	

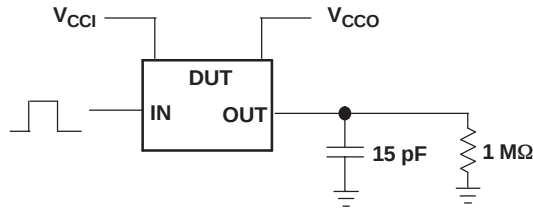
(1) Power dissipation capacitance per transceiver

OPERATING CHARACTERISTICS (continued) $T_A = 25^\circ\text{C}$, $V_{CCA} = 3.3\text{ V}$

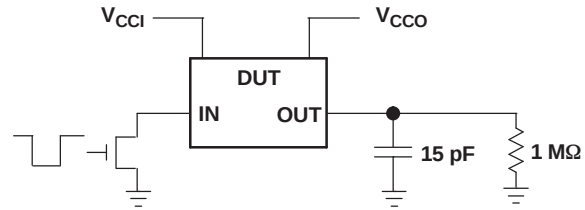
PARAMETER			TEST CONDITIONS	V_{CCB} TYP						UNIT
				1.2 V	1.5 V	1.8 V	2.5 V	3 V	3.3 V	
$C_{pdB}^{(1)}$	A-port input, B-port output	DATA Enabled	$C_L = 0$, $f = 10\text{ MHz}$, $t_r = t_f = 1\text{ ns}$	25.2	25.6	26	27.1	28	28.5	pF
	B-port input, A-port output	CLK Enabled		26	25.8	25.8	26.3	26.8	27	
	B-port input, A-port output	DATA Enabled		13.7	12.1	11.4	12.2	12.7	13.2	
	A-port input, B-port output	DATA Disabled		0.3	0.1	0.1	0.1	0.1	0.1	
	B-port input, A-port output	CLK Disabled		0.3	0.1	0.1	0.1	0.1	0.1	
	B-port input, A-port output	DATA Disabled		1.2	1.2	1.1	1	0.9	0.8	

**Figure 7. Typical ASIP EMI Filter Frequency Response**

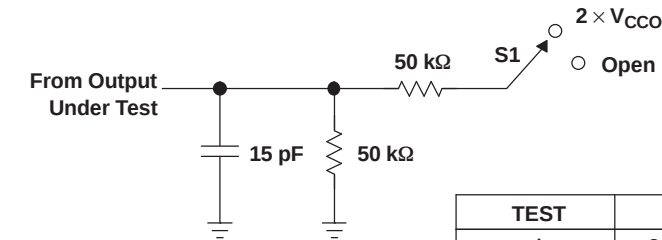
PARAMETER MEASUREMENT INFORMATION



DATA RATE, PULSE DURATION, PROPAGATION DELAY,
OUTPUT RISE AND FALL TIME MEASUREMENT USING
A PUSH-PULL DRIVER

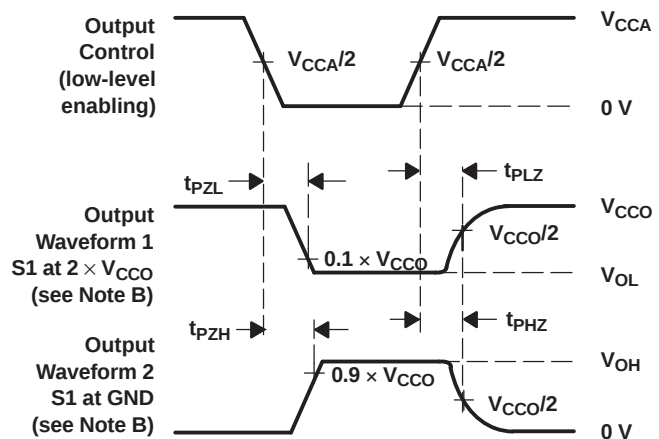
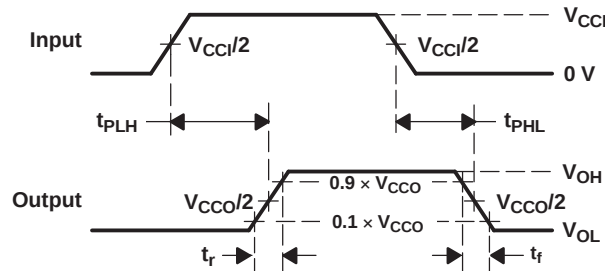
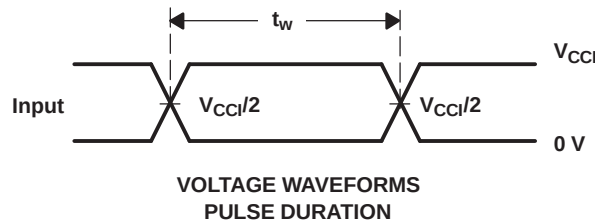


DATA RATE, PULSE DURATION, PROPAGATION DELAY,
OUTPUT RISE AND FALL TIME MEASUREMENT USING
AN OPEN-DRAIN DRIVER



LOAD CIRCUIT FOR ENABLE/DISABLE
TIME MEASUREMENT

TEST	S1
t_{PZL}/t_{PLZ} t_{PHZ}/t_{PZH}	$2 \times V_{CCO}$ Open



- C_L includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: $PRR \leq 10$ MHz, $Z_O = 50 \Omega$, $dv/dt \geq 1$ V/ns.
- The outputs are measured one at a time, with one transition per measurement.
- t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- t_{PZL} and t_{PZH} are the same as t_{en} .
- t_{PLH} and t_{PHL} are the same as t_{pd} .
- V_{CCI} is the V_{CC} associated with the input port.
- V_{CCO} is the V_{CC} associated with the output port.
- All parameters and waveforms are not applicable to all devices.

PARAMETER MEASUREMENT INFORMATION (continued)**Figure 8. Load Circuit and Voltage Waveforms**

APPLICATION INFORMATION

The TXS0206 has integrated pullup resistors on the data and command ports and their values dynamically change. When the port is in a low signal state, there is a nominal pullup resistor value of 40 k Ω , and power consumption is minimized. When the port is in a high signal state, the nominal pullup resistor value changes to 4 k Ω , and simultaneous switching performance is improved as a result. The threshold at which the resistance changes is approximately $V_{CC}/2$.

When using the TXS0206 device with MMCs, SD, and Memory Stick™ to ensure that a valid receiver input voltage high (V_{IH}) is achieved, the value of any pulldown resistors (external or internal to a memory card) must not be smaller than a 10-k Ω value. The impact of adding too heavy (i.e., <10-k Ω value) a pulldown resistor to the data and command lines of the TXS0206 device and the resulting 4-k Ω pullup / 10-k Ω pulldown voltage divider network has a direct impact on the V_{IH} of the signal being sent into the memory card and its associated logic.

The resulting V_{IH} voltage for the 10-k Ω pulldown resistor value would be:

$$V_{CC} \times 10 \text{ k}\Omega / (10 \text{ k}\Omega + 4 \text{ k}\Omega) = 0.714 \times V_{CC}$$

This is marginally above a valid input high voltage for a 1.8-V signal (i.e., $0.65 \times V_{CC}$).

The resulting V_{IH} voltage for 20-k Ω pulldown resistor value would be:

$$V_{CC} \times 20 \text{ k}\Omega / (20 \text{ k}\Omega + 4 \text{ k}\Omega) = 0.833 \times V_{CC}$$

Which is above the valid input high voltage for a 1.8-V signal of $0.65 \times V_{CC}$.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TXS0206YFPR	ACTIVE	DSBGA	YFP	20	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

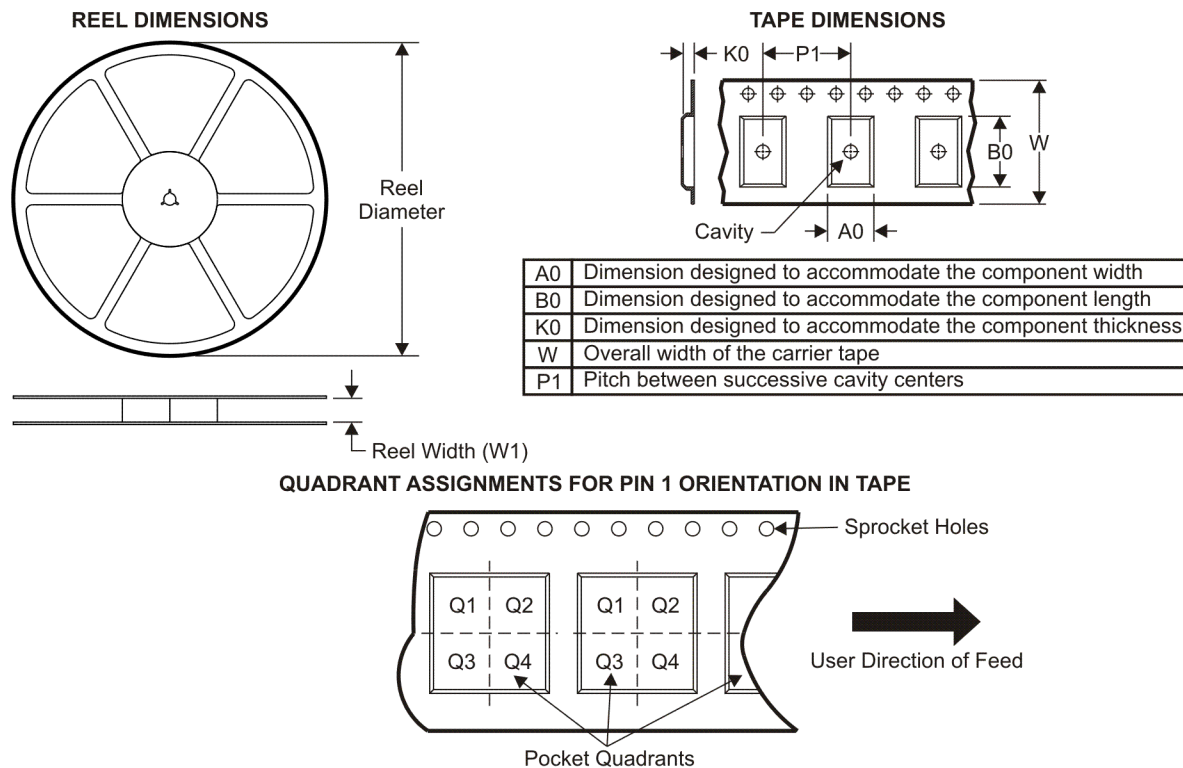
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

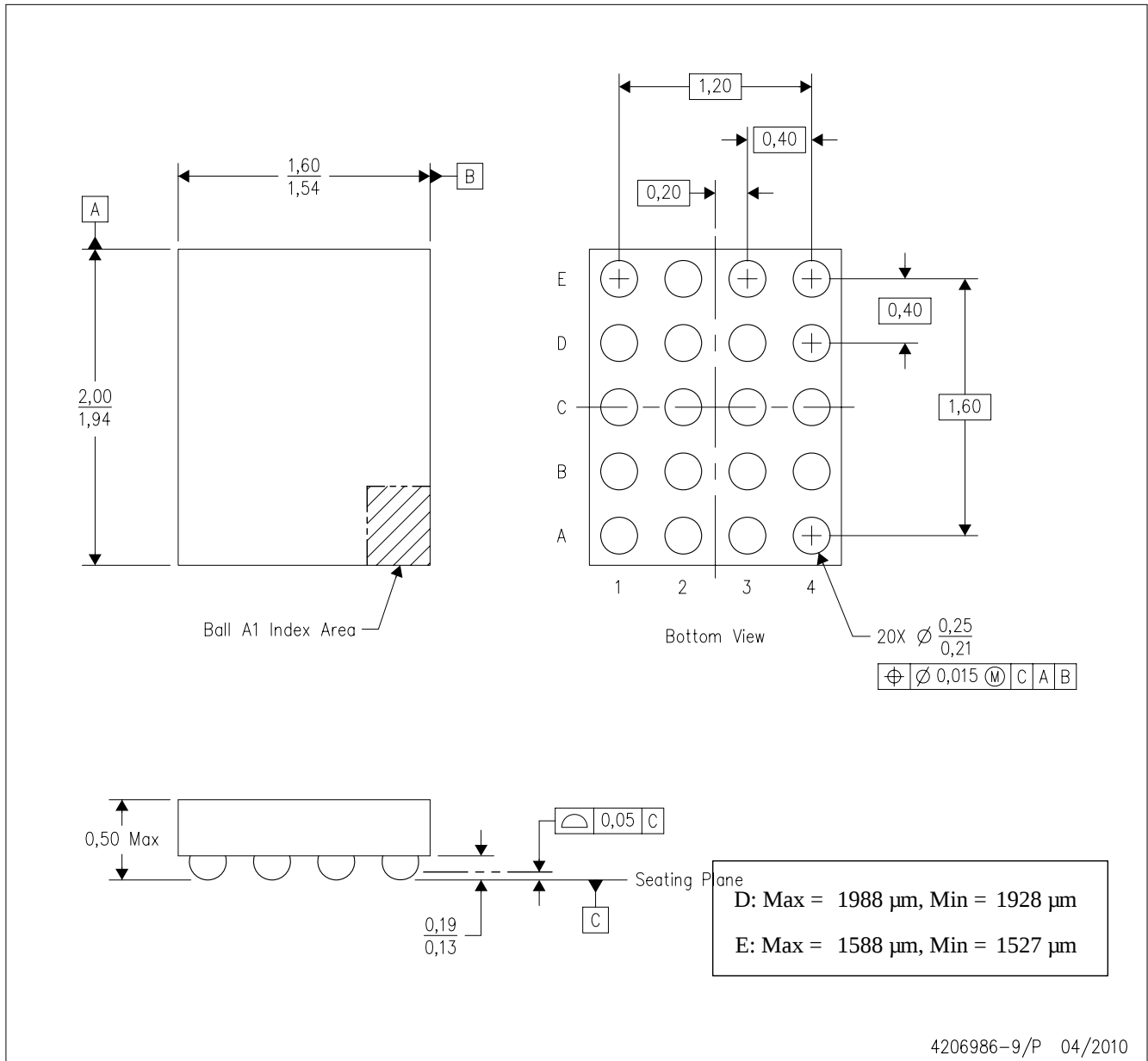
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXS0206YFPR	DSBGA	YFP	20	3000	180.0	8.4	1.65	2.05	0.6	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXS0206YFPR	DSBGA	YFP	20	3000	220.0	220.0	34.0



- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - NanoFree™ package configuration.
 - This is a Pb-free solder ball design.

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